#### NATL SEMICOND (LINEAR)



T-52-17

# DS1631/DS3631/DS1632/DS3632/DS1633/DS3633/ DS1634/DS3634 CMOS Dual Peripheral Drivers

### **General Description**

The DS1631 series of dual peripheral drivers was designed to be a universal set of interface components for CMOS

Each circuit has CMOS compatible inputs with thresholds that track as a function of V<sub>CC</sub> (approximately ½ V<sub>CC</sub>). The inputs are PNPs providing the high impedance necessary for interfacing with CMOS.

Outputs have high voltage capability, minimum breakdown voltage is 56V at 250 µA.

The outputs are Darlington connected transistors. This allows high current operation (300 mA max) at low internal V<sub>CC</sub> current levels since base drive for the output transistor is obtained from the load in proportion to the required loading conditions. This is essential in order to minimize loading on the CMOS logic supply.

Typical  $V_{CC} = 5V$  power is 28 mW with both outputs ON. V<sub>CC</sub> operating range is 4.5V to 15V.

The circuit also features output transistor protection if the V<sub>CC</sub> supply is lost by forcing the output into the high impedance OFF state with the same breakdown levels as when Vcc was applied.

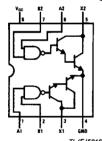
Pin-outs are the same as the respective logic functions found in the following popular series of circuits: DS75451, DS75461. This feature allows direct conversion of present systems to the MM74C CMOS family and DS1631 series circuits with great power savings.

The DS1631 series is also TTL compatible at  $V_{CC} = 5V$ .

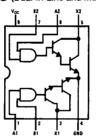
#### **Features**

- CMOS compatible inputs
- High impedance inputs
- PNP's 56V min
- High output voltage breakdown
- 300 mA max
- High output current capability
- Same pin-outs and logic functions as DS75451 and
- DS75461 series circuits
- Low V<sub>CC</sub> power dissipation (28 mW both outputs "ON" at 5V)

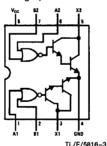
#### Connection Diagrams (Dual-In-Line and Metal Can Packages)



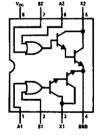
Top View



**Top View** Order Number DS1632J-8 or DS3632N



**Top View** Order Number DS1633J-8 or DS3633N

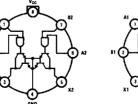


TL/F/5816-4

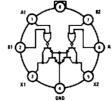
**Top View** Order Number DS1634J-8 or DS3634N

Order Number DS1631J-8 or DS3631N

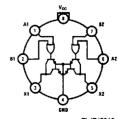
See NS Package Number J08A or N08E



TL/F/5816-6



TL/F/5816-7 **Top View** 



TL/F/5816-8

**Top View** 

(Pin 4 is electrically connected to the

TL/F/5816-5

Order Number DS1631H

#### **Top View**

(Pin 4 is electrically connected to the

Order Number DS1632H

(Pin 4 is electrically connected to the Order Number DS1633H See NS Package Number H08C

#### **Top View**

(Pin 4 is electrically connected to the

Order Number DS1634H

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Absolute Maximum R	Operating Conditions				
If Military/Aerospace specified please contact the National Office/Distributors for availabilit	Semiconductor Sales	Supply Voltage, V <sub>CC</sub> DS1631/DS1632/	<b>Min</b> 4.5	<b>Max</b> 15	Units V
Supply Voltage	16V	DS1633/DS1634	1.0		•
Voltage at Inputs	$-0.3V$ to $V_{CC} + 0.3V$				
Output Voltage	56V	DS3631/DS3632/	4.75	15	٧
Storage Temperature Range	-65°C to +150°C	DS3633/DS3634			
Maximum Power Dissipation* at 25 Cavity Package Molded Package TO-5 Package	°C 1133 mW 1022 mW 787 mW	Temperature, T <sub>A</sub> DS1631/DS1632/ DS1633/DS1634	-55	+ 125	°C
Lead Temperature (Soldering, 4 sec *Derate cavity package 7.6 mW/°C above 8.2 mW/°C above 25°C; derate TO-5 packag	25°C; derate molded package	DS3631/DS3632/ DS3633/DS3634	0	+70	٠c

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# Electrical Characteristics (Notes 2 and 3)

Symbol	Parameter		Conditions		Min	Тур	Max	Units
ALL CIR	CUITS							
V <sub>IH</sub> Logical "1" Input Voltage		(Figure 1) V <sub>CC</sub> = 5V V <sub>CC</sub> = 10V		3.5	2.5		٧	
				8.0	5		٧	
		V <sub>CC</sub> = 15V			12.5	7.5		٧
$V_{IL}$	Logical "0" Input Voltage	( <i>Figure 1</i> ) V <sub>CC</sub> = 5V			2.5	1.5	٧	
			V <sub>CC</sub> = 10V			5.5	2.0	٧
		V <sub>CC</sub> = 15V				7.5	2.5	٧
lін	Logical "1" Input Current	$V_{CC} = 15V, V_{JN} = 15V$	/, (Figure 2)			0.1	10	μΑ
I <sub>Ι</sub> L	Logical "0" Input Current	V <sub>IN</sub> = 0.4V, ( <i>Figure 3</i> )	$V_{CC} = 5V$			-50	-120	μΑ
			V <sub>CC</sub> = 15V			-200	-360	μΑ
V <sub>OH</sub>	Output Breakdown Voltage	$V_{CC} = 15V, I_{OH} = 250$	) μΑ, ( <i>Figure 1</i> )		56	65		٧
V <sub>OL</sub>	Output Low Voltage	V <sub>CC</sub> = Min, ( <i>Figure 1</i> ), DS1631, DS1632, I <sub>OL</sub> = 100 mA				0.85	1.1	V
		DS1633, DS1634	I <sub>OL</sub> = 300 mA			1.1	1.4	v
	V <sub>CC</sub> = Min, ( <i>Figure 1</i> ), DS3631, DS3632, I <sub>OL</sub> = 100 mA				0.85	1.0	v	
	DS3633, DS3634 I <sub>OL</sub> = 300 mA				1.1	1.3	v	
DS1631/	/DS3631		<u> </u>					
I <sub>CC(0)</sub>	Supply Currents	V <sub>IN</sub> = 0V, (Figure 4)	V <sub>CC</sub> = 5V	Output Low		7	11	mA
			V <sub>CC</sub> = 15V	Both Drivers		14	20	mA
I <sub>CC(1)</sub>		(Figure 4)	$V_{CC} = 5V, V_{IN} = 5V$	Output High		2	3	mA
		1	V <sub>CC</sub> = 15V, V <sub>IN</sub> = 15V	Both Drivers		7.5	10	mA
t <sub>PD1</sub>	Propagation to "1"	$V_{CC} = 5V$ , $T_A = 25^{\circ}C$ , $C_L = 15$ pF, $R_L = 50\Omega$ , $V_L = 10V$ , (Figure 5)				500		ns
t <sub>PD0</sub>	Propagation to "0"	$V_{CC} = 5V$ , $T_A = 25^{\circ}C$ , $C_L = 15 \text{ pF}$ , $R_L = 50\Omega$ , $V_L = 10V$ , (Figure 5)				750		ns
DS1632/	/DS3632							
ICC(0)	Supply Currents	(Figure 4)	V <sub>CC</sub> = 5V, V <sub>IN</sub> = 5V	Output Low	I	8	12	mA
			V <sub>CC</sub> = 15V, V <sub>IN</sub> = 15V			18	23	mA
I <sub>CC(1)</sub>		V <sub>IN</sub> = 0V, (Figure 4)	V <sub>CC</sub> = 5V	Output Link		2.5	3.5	mA
			V <sub>CC</sub> = 15V	Output High	1	9	14	mA
t <sub>PD1</sub>	Propagation to "1"	$V_{CC}=5$ V, $T_{A}=25$ °C, $C_{L}=15$ pF, $R_{L}=50\Omega$ , $V_{L}=10$ V, (Figure 5)				500		ns
t <sub>PD0</sub>	Propagation to "0"	$V_{CC} = 5V$ , $T_A = 25$ °C, $C_L = 15$ pF, $R_L = 50\Omega$ , $V_L = 10V$ , (Figure 5)				750		ns

## Electrical Characteristics (Notes 2 and 3) (Continued)

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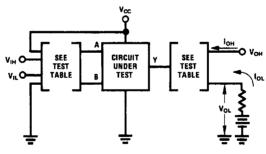
Symbol	Parameter	Conditions			Min	Тур	Max	Units	
DS1633/DS3633									
ICC(0)	Supply Currents	V <sub>IN</sub> = 0V, (Figure 4)	V <sub>CC</sub> = 5V	Output Low		7.5	12	mA	
55(0)	'''		V <sub>CC</sub> = 15V	1		16	23	mA	
ICC(1)		(Figure 4)	$V_{CC} = 5V, V_{IN} = 5V$	Output High		2	4	mA	
00(.,			V <sub>CC</sub> = 15V, V <sub>IN</sub> = 15V	1		7.2	15	mA	
t <sub>PD1</sub>	Propagation to "1"	$V_{CC} = 5V$ , $T_A = 25^{\circ}C$ , $C_L = 15 \text{ pF}$ , $R_L = 50\Omega$ , $V_L = 10V$ , (Figure 5)				500		ns	
t <sub>PD0</sub>	Propagation to "0"	$V_{CC} = 5V$ , $T_A = 25^{\circ}C$ , $C_L = 15 \text{ pF}$ , $R_L = 50\Omega$ , $V_L = 10V$ . (Figure 5)				750		ns	
DS1634/	DS3634								
ICC(0)	Supply Currents	(Figure 4)	V <sub>CC</sub> = 5V, V <sub>IN</sub> = 5V	Output Low		7.5	12	mA	
(-)			V <sub>CC</sub> = 15V, V <sub>IN</sub> = 15V	]		18	23	mA	
ICC(1)		V <sub>IN</sub> = 0V, (Figure 4)	V <sub>CC</sub> = 5V	Output High		3	5	mA	
00(.)			V <sub>CC</sub> = 15V	]		11	18	mA	
t <sub>PD1</sub>	Propagation to "1"	$V_{CC} = 5V$ , $T_A = 25^{\circ}C$ , $C_L = 15 \text{ pF}$ , $R_L = 50\Omega$ , $V_L = 10V$ , (Figure 5)				500		ns	
t <sub>PD0</sub>	Propagation to "0"	$V_{CC} = 5V$ , $T_A = 25^{\circ}C$ , $C_L = 15 \text{ pF}$ , $R_L = 50\Omega$ , $V_L = 10V$ , (Figure 5)				750		ns	

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

Note 2: Unless otherwise specified min/max limits apply across the -55°C to +125°C temperature range for the DS1631, DS1632, DS1633 and DS1634 and across the 0°C to +70°C range for the DS3631, DS3632, DS3633 and DS3634. All typical values are for T<sub>A</sub> = 25°C.

Note 3: All currents into device pins shown as positive, out of device pins as negative, all voltages referenced to ground unless otherwise noted. All values shown as max or min on absolute value basis.

### **Test Circuits**



TL/F/5816-9

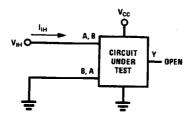
	Input	<b>011</b>	Output			
Circuit	Under Test	Other	Apply	Measure		
DS3631	V <sub>IH</sub> V <sub>IL</sub>	V <sub>IH</sub> V <sub>CC</sub>	I <sub>OH</sub>	V <sub>OL</sub>		
DS3632	V <sub>IH</sub> V <sub>IL</sub>	V <sub>IH</sub> V <sub>CC</sub>	I <sub>OL</sub>	V <sub>OL</sub> V <sub>OH</sub>		
DS3633	V <sub>IH</sub> V <sub>IL</sub>	GND V <sub>IL</sub>	lон lol	V <sub>OH</sub> V <sub>OL</sub>		
DS3634	V <sub>IH</sub> V <sub>IL</sub>	GND V <sub>IL</sub>	loh loh	V <sub>OL</sub> V <sub>OH</sub>		

Note: Each input is tested separately.

FIGURE 1. VIH, VIL, VOH, VOL

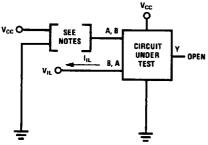
## Test Circuits (Continued)

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Each input is tested separately.

FIGURE 2. I<sub>IH</sub>



TL/F/5816-11

V<sub>CCH</sub> UPEN X X B B GND

TL/F/5816-10

TL/F/5816-12

Both gates are tested simultaneously.

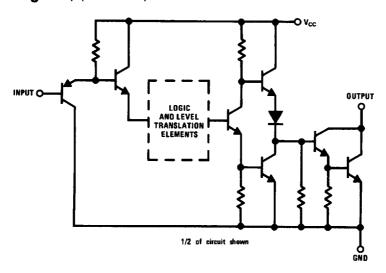
FIGURE 4. I<sub>CC</sub> for AND and NAND Circuits

Note A: Each input is tested separately.

Note B: When testing DS1633 and DS1634 input not under test is grounded. For all other circuits it is at  $V_{CC}$ .

FIGURE 3. I<sub>IL</sub>

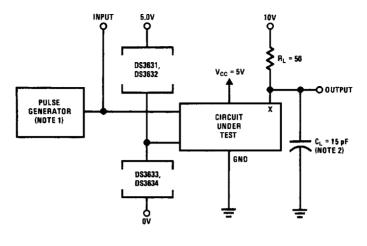
## Schematic Diagram (Equivalent Circuit)



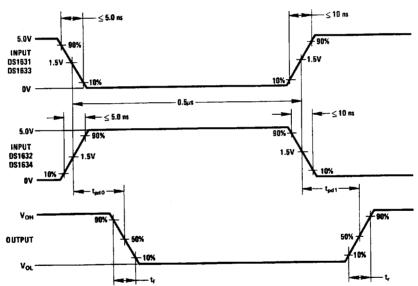
TL/F/5816-15

## **Switching Time Waveforms**

# NATL SEMICOND (LINEAR)



TL/F/5816-13



TL/F/5816-14

Note 1: The pulse generator has the following characteristics: PRR = 500 kHz,  $Z_{OUT} \approx 50\Omega$ 

Note 2: CL includes probe and jig capacitance

FIGURE 5. Switching Times